

ST3485EB, ST3485EC, ST3485EI, ST3485EIY

3.3 V powered, 15 kV ESD protected, up to 12 Mbps RS-485/ RS-422 transceiver

Datasheet - production data



Features

- ESD protection
 - ±15 kV IEC 61000-4-2 air discharge
- ±8 kV IEC 61000-4-2 contact discharge
 Operate from a single 3.3 V supply no
- Interoperable with 5 V logic
- 1 µA low current shutdown mode max.
- Guaranteed 12 Mbps data rate
- -7 to 12 V common mode input voltage range
- Half duplex versions available
- Industry standard 75176 pinout
- Current limiting and thermal shutdown for driver overload protection
- Guaranteed high receiver output state for floating inputs with no signal present
- Allow up to 64 transceivers on the bus
- Available in SO8 package
- Automotive grade (ST3485EIY)

Description

The ST3485EB/EC/EI/EIY device is ±15 kV ESD protected, 3.3 V low power transceiver for RS-485 and RS-422 communications. The device contains one driver and one receiver in half duplex configuration.

The ST3485E device transmits and receives at a guaranteed data rate of at least 12 Mbps.

All transmitter outputs and receiver inputs are protected to ± 15 kV IEC 61000-4-2 air discharge.

The driver is short-circuit current limited and is protected against excessive power dissipation by thermal shutdown circuitry that places the driver outputs into a high impedance state.

Table 1: Device summary

Order code	Temp range	Package	Packaging		
ST3485ECDR	0 to 70 °C				
ST3485EBDR	-40 to 85 °C	SO8	2500 parts		
ST3485EIDT	40 1- 405 00	(tape and reel)	per reel		
ST3485EIYDT	-40 to 125 °C	,			

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This is information on a product in full production.

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1 Pin configuration



Table 2: Pin description

Pin n°	Symbol	Name and function
1	RO	Receiver output. If A > B by 200 mV, RO will be high; if A < B by 200 mV, RO will be low.
2	RE	Receiver output enable. RO is enabled when \overline{RE} is low; RO is high impedance when \overline{RE} is high. If \overline{RE} is high and DE is low, the device will enter a low power shutdown mode.
3	DE	Driver output enable. The driver outputs are enabled by bringing DE high. They are high impedance when DE is low. If \overline{RE} is high DE is low, the device will enter a low-power shutdown mode. If the driver outputs are enabled, the part functions as line driver, while they are high impedance, it functions as line receivers if \overline{RE} is low.
4	DI	Driver input. A low on DI forces output A low and output B high. Similarly, a high on DI forces output A high and output B low.
5	GND	Ground
6	А	Non-inverting receiver input and non-inverting driver output.
7	В	Inverting receiver input and inverting driver output.
8	VCC	Supply voltage: $V_{CC} = 3 V$ to 3.6 V.



2 Truth tables

Table 3: Truth table (driver)								
	Inputs		Outputs					
RE	DE	DI	В	А	Mode			
x		н	н	L	Н			
^	Π	L	Н	L	Normal			
L		V	7	7				
Н	L	^	X Z Z	ZZZ				Shutdown

Note: X = "don't care"; Z = high impedance

	Inputs		Output	
RE	DE	A-B	RO	Mode
		≥ 0.2 V	Н	
L		≤ -0.2 V	L	Normal
	L	Inputs open	Н	
Н		Х	Z	Shutdown

Note: X = "don't care"; Z = high impedance



3 Maximum ratings

Absolute maximum ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

Symbol	Parameter	Value	Unit
Vcc	Supply voltage	7	
VI	Control input voltage (RE , DE)	-0.3 to 7	
VDI	Driver input voltage (DI)	-0.3 to 7	V
Vdo	Driver output voltage (A, B)	±14	
V _{RI}	Receiver input voltage (A, B)	±14	
V _{RO}	Receiver output voltage (RO)	-0.3 to (Vcc + 0.3)	
	HBM: human body model for the line inputs (A and B) $^{(1)}$	12	
ESD	HBM: human body model for the logic inputs (DI, DE, $\overline{\rm RE}$) $^{(1)}$	4	kV
	Supply voltage 7 Control input voltage (RE , DE) -0.3 to 7 Driver input voltage (DI) -0.3 to 7 Driver output voltage (A, B) ±14 Receiver input voltage (A, B) ±14 Receiver output voltage (RO) -0.3 to (V _{cc} + 0.3) HBM: human body model for the line inputs (A and B) ⁽¹⁾ 12		
	CDM: charged device model ⁽²⁾	$ \begin{array}{c ccccc} & 7 \\ & -0.3 \text{ to } 7 \\ \hline & -0.3 \text{ to } 7 \\ \hline & \pm 14 \\ \hline & \pm 14 \\ \hline & -0.3 \text{ to } (V_{CC} + 0.3) \\ \hline & 12 \\ \hline & 4 \\ \hline & (1) & 2 \\ \hline \end{array} $	

Table 5: Absolute maximum ratings

Notes:

 $^{(1)}$ Human body model: 100 pF discharged through a 1.5 k Ω resistor between two pins of the device, done for all couples of pin combinations with other pins floating.

⁽²⁾Charged device model: all pins plus package are charged together to the specified voltage and then discharged directly to ground.



4 **Electrical characteristics**

Table 6: Electrical characteristics (VCC = 3 V to 3.6 V, TA = 0 to 70 °C for ST3485ECDR, TA = -40 to 85 °C for ST3485EBDR, TA = -40 to 125 °C for ST3485EIDT and ST3485EIYDT, unless otherwise specified. Typical values are referred to TA = 25 °C)

Symbol	Parameter	Test conditions			Тур.	Max.	Unit
ISUPPLY Vcc power supp		No load,	$\frac{DE = V_{CC}}{RE} = 0 \; V \; or \; V_{CC}$		1.3	2.2	mA
	V _{CC} power supply current	$DI = 0 V \text{ or } V_{CC}$	$\frac{DE = 0 \text{ V},}{RE} = 0 \text{ V}$	_	1.2	1.9	
Ishdn	Shutdown supply current	$DE = 0 V$, $\overline{RE} = V_{CC}$, $DI = 0 V$ or V_{CC}			0.002	1	μA

Table 7: Logic input electrical characteristics (VCC = 3 V to 3.6 V, TA = 0 to 70 °C for ST3485ECDR, TA = -40 to 85 °C for ST3485EBDR, TA = -40 to 125 °C for ST3485EIDT and ST3485EIYDT, unless otherwise specified. Typical values are referred to TA = 25 °C)

Symbol	Parameter	Test conditions			Тур.	Max.	Unit
VIL	Input logic threshold low	DE, DI, RE			1.3	0.8	v
VIH	Input logic threshold high	DE, DI, RE	2			V	
lin1	Logic input current	DE, DI, RE				±2.0	μA
luur	Input ourrent (A_B)	DE = 0 V, Vcc= 0 or 3.6 V	V _{IN} = 12 V			1	mA
lin2	Input current (A, B)	$DE = 0.0$, $V_{CC} = 0.013.8$ V $V_{IN} = -7$ V				-0.8	IIIA

Table 8: Transmitter electrical characteristics (VCC = 3 V to 3.6 V, TA = 0 to 70 °C for ST3485ECDR, TA = -40 to 85 °C for ST3485EBDR, TA = -40 to 125 °C for ST3485EIDT and ST3485EIYDT, unless otherwise specified. Typical values are referred to TA = 25 °C)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
		R _L = 100 Ω (RS-422) (<i>Figure 2</i>)	2			
Vod	Differential drive output	R _L = 54 Ω (RS-485) (<i>Figure 2</i>)	1.5			
		R _L = 60 Ω (RS-485) (<i>Figure 3</i>)	1.5			
ΔV_{OD}	Change in magnitude of driver differential output voltage for complementary output states ⁽¹⁾	R∟= 54 Ω or 100 Ω (<i>Figure 2</i>)		_	0.2	V
V _{oc}	Driver common mode output voltage	R _L = 54 Ω or 100 Ω (<i>Figure 2</i>)			3	
ΔV_{OC}	Change in magnitude of driver common mode output voltage ⁽¹⁾	R∟= 54 Ω or 100 Ω (<i>Figure 2</i>)			0.2	
Iosd	Driver short-circuit output current				±250	mA

Notes:

 $^{(1)}\Delta V_{OD}$ and ΔV_{OC} are the changes in V_OD and V_OC, respectively, when the DI input changes state.

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Table 9: Receiver electrical characteristics (VCC = 3 V to 3.6 V, TA = 0 to 70 °C for ST3485ECDR, TA = -40 to 85 °C for ST3485EBDR, TA = -40 to 125 °C for ST3485EIDT and ST3485EIYDT, unless otherwise specified. Typical values are referred to TA = 25 °C)

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Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit			
VTH	Receiver differential threshold voltage	$V_{CM} = -7 V$ to 12 V, DE = 0	-0.2		0.2	V			
ΔV_{TH}	Receiver input hysteresis	V _{CM} = 0 V		70		mV			
V _{OH}	Receiver output high voltage	I _{OUT} = -4 mA, V _{ID} = 200 mV (<i>Figure 4</i>)	2			V			
Vol	Receiver output low voltage	Iout = 4 mA, V _{ID} = -200 mV (<i>Figure 4</i>)			0.4	V			
I _{OZR}	3-state (high impedance) output current at receiver	V_{CC} = 3.6 V, V_{O} = 0 V to V_{CC}			±1	μA			
R _{RIN}	Receiver input resistance	$V_{CM} = -7 V$ to 12 V	24			kΩ			
IOSR	Receiver short-circuit current	V _{RO} = 0 V to V _{CC}	7		60	mA			

Table 10: Driver switching characteristics (VCC = 3 V to 3.6 V, TA = 0 to 70 °C for ST3485ECDR, TA = -40 to 85 °C for ST3485EBDR, TA = -40 to 125 °C for ST3485EIDT and ST3485EIYDT, unless otherwise specified. Typical values are referred to TA = 25 °C)

	515465ETTDT, unless otherwise specified. Typical values are referred to TA = 25 C)								
Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit			
DR	Maximum data rate		12	15		Mbps			
t _{DD}	Differential output delay	R_L = 60 Ω, C_L = 15 pF (<i>Figure 5</i> and <i>Figure 6</i>)		18	30				
tтр	Differential output transition time	R_L = 60 Ω, C_L = 15 pF (<i>Figure 5</i> and <i>Figure 6</i>)		12	20				
tplh tphl	Propagation delay	R _L = 27 Ω, C _L = 15 pF (<i>Figure 9</i> and <i>Figure 10</i>)		18	30				
t _{PDS}	t _{PLH} - t _{PHL} driver propagation delay skew ⁽¹⁾	R _L = 27 Ω, C _L = 15 pF (<i>Figure 9</i> and <i>Figure 10</i>)		2	5				
t _{PZL}	Output enable time	R _L = 110 Ω (<i>Figure 11</i> and <i>Figure 12</i>)		19	35				
t PZH	Output enable time	R_L = 110 Ω (<i>Figure 7</i> and <i>Figure 8</i>)		30	50	ns			
t PHZ	Output disable time	R _L = 110 Ω (<i>Figure</i> 7 and <i>Figure</i> 8)		19	35				
t _{PLZ}	Output disable time	R _L = 110 Ω (<i>Figure 11</i> and <i>Figure 12</i>)		30	50				
tskew	Differential output delay skew			1	3				
t PSH	Driver enable from shutdown to output high	$R_L = 110 \Omega (Figure 7 and Figure 8)$		30	50				
tpsl	Driver enable from shutdown to output low	$R_L = 110 \Omega$ (<i>Figure 11</i> and <i>Figure 12</i>)		19	35				

Notes:

 $^{(1)}\mbox{Measured on }\mbox{tplh}(A)\mbox{-tphL}(A)\mbox{} and \mbox{tplh}(B)\mbox{-tphL}(B)\mbox{} .$



Table 11: Receiver switching characteristics (VCC = 3 V to 3.6 V, TA = 0 to 70 °C for ST3485ECDR, TA = -40 to 85 °C for ST3485EBDR, TA = -40 to 125 °C for ST3485EIDT and ST3485EIYDT, unless otherwise specified. Typical values are referred to TA = 25 °C)

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Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
trplh, trphl	Propagation delay	$V_{ID} = 0 V$ to 3 V, $C_L = 15 pF$ (<i>Figure 13</i> and <i>Figure 14</i>)		30	50	
trpds	t _{RPLH} - t _{RPHL} receiver propagation delay skew	V _{ID} = 0 V to 3 V, C _L = 15 pF (<i>Figure 13</i> and <i>Figure 14</i>)		1	3	
t _{PRZL}	Receiver output enable time to low level	$C_L = 15 \text{ pF} (Figure 15 \text{ and } Figure 17)$		10	20	
tprzh	Receiver output enable time to high level	$C_L = 15 \text{ pF} (Figure 15 \text{ and } Figure 16)$		10	20	ns
t _{PRHZ}	Receiver output disable time from high level	$C_L = 15 \text{ pF} (Figure 15 \text{ and } Figure 18)$	_	10	20	
tprlz	Receiver output disable time from low level	$C_L = 15 \text{ pF} (Figure 15 \text{ and } Figure 19)$		10	20	
tprsh	Receiver output enable time from shutdown to high level	$C_L = 15 \text{ pF} (Figure 15 \text{ and } Figure 16)$		10	20	
t PRSL	Receiver output enable time from shutdown to low level	C _L = 15 pF (<i>Figure 15</i> and <i>Figure 17</i>)		20	40	μs

Notes:

1. ΔV_{OD} and ΔV_{OC} are the changes in V_{OD} and V_{OC} , respectively, when the DI input changes state.

2. Measured on |tplH(A) - tpHL(A)| and |tpLH(B) - tpHL(B)|.

3. The transceivers are put into shutdown by bring \overline{RE} high and DE low. If the input are in state for less than 80 ns, the part are guaranteed not to enter shutdown. If the inputs are in this state for at least 300 ns, the parts are guaranteed to have entered shutdown.









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1. The input pulse is supplied by a generator with the following characteristics: PRR = 250 kHz, 50 % duty cycle, tr \leq 6.0 ns, Z₀ = 50 Ω .

2. C_L includes probe and stray capacitance





1. The input pulse is supplied by a generator with the following characteristics: PRR = 250 kHz, 50 % duty cycle, tr $\leq 6.0 \text{ ns}$.

2. C_L includes probe and stray capacitance



ST3485EB, ST3485EC, ST3485EI, ST3485EIY



1. t_{PZH} is valid if the driver is initially disabled (RE is high), t_{PSH} is valid if the driver is initially in shutdown mode (RE is low).



- 1. The input pulse is supplied by a generator with the following characteristics: PRR = 250 kHz, 50 % duty cycle, tr $\leq 6.0 \text{ ns}$.
- 2. C_L includes probe and stray capacitance



ST3485EB, ST3485EC, ST3485EI, ST3485EIY





- 1. The input pulse is supplied by a generator with the following characteristics: PRR = 250 kHz, 50 % duty cycle, tr \leq 6.0 ns. C_L includes probe and stray capacitance
- 2.





t_{PZL} is valid if the driver is initially disabled (RE is high), t_{PSL} is valid if the driver is initially in shutdown mode (RE is low).



1. The input pulse is supplied by a generator with the following characteristics: PRR = 250 kHz, 50 % duty cycle, tr $\leq 6.0 \text{ ns}$.



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1. The input pulse is supplied by a generator with the following characteristics: PRR = 250 kHz, 50 % duty cycle, tr \leq 6.0 ns.

2. C_L includes probe and stray capacitance







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Test circuits and typical characteristics







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6 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK[®] is an ST trademark.



6.1 SO8 package information



Table 12: SO8 mechanical data

	Dimensions						
Ref.	Millimeters			Inches			
	Min.	Тур.	Max.	Min.	Тур.	Мах	
А			1.75			0.069	
A1	0.10		0.25	0.004		0.010	
A2	1.25			0.049			
b	0.28		0.48	0.011		0.019	
С	0.17		0.23	0.007		0.010	
D	4.80	4.90	5.00	0.189	0.193	0.197	
E	5.80	6.00	6.20	0.228	0.236	0.244	
E1	3.80	3.90	4.00	0.150	0.154	0.157	
е		1.27			0.050		
h	0.25		0.50	0.010		0.020	
L	0.40		1.27	0.016		0.050	
L1		1.04			0.040		
k	1°		8°	1°		8°	
ccc			0.10			0.004	



6.2 SO8 tape and reel information



1. Drawing not to scale

	Dimensions						
Symbol	mm			inch			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
А			330			12.992	
С	12.8		13.2	0.504		0.519	
D	20.2			0.795			
Ν	60			2.362			
Т			22.4			0.882	
Ao	8.1	_	8.5	0.319	_	0.335	
Во	5.5		5.9	0.216		0.232	
Ko	2.1		2.3	0.082		0.090	
Po	3.9		4.1	0.153		0.161	
Р	7.9		8.1	0.311		0.319	



7 Ordering information

Table 14: Order codes					
Order code	Temperature range	Package	Packaging	Marking	
ST3485ECDR	0 to 70 °C			3485EC	
ST3485EBDR	-40 to 85 °C	<u> </u>	Tana and real	3485EB	
ST3485EIDT	-40 to 125 °C	SO8 Tape and reel		3485EI	
ST3485EIYDT ⁽¹⁾	-40 to 125 °C (automotive grade)			3485EIY	

Notes:

⁽¹⁾Qualification and characterization according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 and Q 002 or equivalent.



8 Revision history

Date	Revision	Changes	
20-Jun-2005	2	Mistake on table 12 $t_{ZL(SHDN)}$ ms ==> μ s.	
30-Aug-2005	3	Remove (TRUE) on title, description has been updated in cover page. The V_{TH} and DV_{TH} values are changed in table 10.	
07-Apr-2006	4	Order codes updated.	
12-Nov-2007	5	Added Table 1.	
18-Dec-2013	6	Updated Features (added SO-8 package, replaced human body model by ±15 kV IEC 61000-4-2 air discharge and IEC 1000-4-2 by IEC 61000-4-2). Updated Description (renamed device to ST3485EB/EC, replaced human body model by ±15 kV IEC 61000-4-2 air discharge). Removed ST3485ECN device from Table 1. Updated title of Table 6, cross-references, replaced human body model (HBM) by ±15 kV IEC 61000-4-2 air discharge and IEC 1000-4-2 by IEC 61000-4-2. Added notes below Table 9. Updated Table 10 to Table 12 (updated data, cross-references). Updated Figure 5 to Figure 16 (updated data, added notes below figures, highlighted some parts of Figure 6 and Figure 12). Removed DIP-8 package from Section 6: "Package information" and whole document. Reformatted Section 6: "Package information" (added Figure 27, Figure 28, Table 13 and Table 14, reversed order of figures and table). Minor corrections throughout document.	
12-Jun-2015	7	Added part number ST3485EIY Added order code ST3485EIYDT and pointed out in Features it is automotive grade. Table 7 and Table 9 through to Table 12: replaced $T_A = -40$ to 85 °C with T_A = 0 to 70 °C (ST3485ECDR), $T_A = -40$ to 85 °C (ST3485EBDR), and $T_A = -40$ to 125 °C (ST3485EIYDT). Updated titles of figures 7, 8, 11, 12, 16, 17, 18, 19, 25, and 26	
15-Mar-2016	8	Table 5: added ESD information Removed "Table 6: ESD performance: transmitter outputs, receiver inputs (A, B)". Added Section 7: "Ordering information"	
02-Aug-2016	9	Added new part number ST3485EI Table 1: "Device summary": added information for new part number ST3485EI. Removed " <i>Note</i> " icons throughout datasheet Section 4: "Electrical characteristics": updated TA information Section 5: "Test circuits and typical characteristics": removed overline bar concerning "RE is low" in note 1 of figures 8 and 12. Table 14: "Order codes": added ST3485EIDT and updated footnote 1 (ST3485EIYDT now qualified).	
25-Aug-2016	10	<i>Table 14: "Order codes"</i> : updated order codes ST3485EBDR and ST3485ECDR.	



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